NUMERICAL SIMULATION OF ION PRODUCTION PROCESSES IN EBIS

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Abstract

The numerical model of EBIS is presented. The calculation of Kr ionization by cooling with Ne ions was carried out taking into account charge exchange, ion heating by electrons, ion-ion energy exchange and ion escape processes. A good agreement with experimental data was observed. According to the model, the processes of Pb ionization in EBIS at close to ultimate parameters (the electron beam current is 10 A and the electron energy is 10 keV, the trap capacity is about $10^{12}$ e) by cooling with Ne ions were simulated.

Introduction

The electron-beam method of multicharge ion production was suggested by E.D.Donets in 1967 [1]. The first attempt to create an Electron-Beam Ion Source (EBIS) theory was undertaken by R.Becker [2] and M.C.Vella in 1981 [3]. A more complete theory of the electron-beam method of multicharge ionization in an ion trap was created by the Livermore EBIT group (M.Levine, M.Penetrante, R.Marrs et al.) [4,5]. Based on these results, we present a simpler numerical model of multicharge ionization in EBIS. Simplifications follow from our previous papers [6,7]. The computer codes describing the Kryon-S experimental data can be used to predict EBIS basic parameters: charge state spectrum, ion-beam current and even ion temperatures.

Physical processes in the trap

According to the Livermore papers, main processes in the EBIS trap are the following:

- electron-impact ionization of ions,
- radiative recombination of ions,
- charge exchange between ions and neutral atoms,
- ion heating by an electron beam,
- ion-ion energy exchange,
- ion confinement in the trap,
- ion escape from the trap.

The processes were considered in detail in previous parers [4,5,8,10].

Numerical model

We suppose that the ionization proceed by single steps:

\[
\frac{dN_i}{dt} = -N_i \lambda_{i-1} + N_{i+1} \lambda_{i+1},
\]

\[
\frac{dN_i}{dt} = N_i \lambda_{i-1} - N_j \lambda_{i-1} \phi_{i-1,j} + \lambda_{i,j} + N_i \lambda_{i-1} - \frac{dN_{i+1}}{dt},
\]

\[
\frac{dN_{i-1}}{dt} = N_i \lambda_{i-1} - N_j \lambda_{i-1} \phi_{i-1,j} + \lambda_{i,j} + N_i \lambda_{i+1} \lambda_{i+1} - \frac{dN_i}{dt},
\]

\[
\frac{dN_{i+1}}{dt} = N_i \lambda_{i+1} - N_j \lambda_{i+1} \phi_{i+1,j} + \lambda_{i,j} + N_i \lambda_{i-1} \lambda_{i-1} - \frac{dN_i}{dt},
\]

where $N_0 \ldots N_Z$ are the ion and atom densities, $\lambda_{0,1}, \lambda_{1,2}, \lambda_{b,1}$, $\lambda_{1,b}, \lambda_{Z,1}, \lambda_{1,Z}$ are the ionization coefficients: $\lambda_{b,1} = \sigma_{b,1} J_e$ is the electron current density, $\sigma_{b,1}$ the ionization cross-section, $\lambda_{1,b}, \lambda_{2,1}, \lambda_{b,1}, \lambda_{1,b}, \lambda_{2,Z}$ are the recombination and charge exchange coefficients: $\lambda_{1,b} \phi_{1,b}$, where $\phi_{1,b} = \sigma_{b,1} J_e$, $\sigma_{b,1}$ is the recombination cross-section, $\lambda_{p} = \sigma_{p} N_{0} \langle V_i \rangle$, $\sigma_{p}$ is the charge exchange cross-section, $N_{0}$ is the density of neutral atoms, $\langle V_i \rangle$ is the mean ion speed,

\[
\frac{dN}{dt} = \lambda_{i} \frac{dN_i}{dt} - \frac{dN_{i+1}}{dt} - \frac{dN}{dt}.
\]

The corresponding energy evolution is described by:

\[
\frac{d(N kT)}{dt} = N_i kT_i \lambda_{i-1} - N_j kT_j \phi_{i-1,j} + \lambda_{i,j} + N_i kT_i \lambda_{i+1} \lambda_{i+1} - \frac{dN}{dt} - \frac{d(N kT)}{dt},
\]

where $kT_i$ is the ion temperature,

\[
\frac{d(N kT)}{dt} \lambda_{eon}^\text{ion}
\]

the rate of ion heating by the electron beam,

\[
\sum_j \frac{d(N kT_j)}{dt} \lambda_{eon}^\text{ion}
\]

the rate of ion-ion energy exchange due to Coulomb collision,

\[
\frac{d(N kT)}{dt} \lambda_{eon}^\text{ion}
\]

the rate of the energy loss due to escaping ions.

Calculations and comparison with experimental results

The dependences of Kr ion densities, electron beam compensation values, Kr ion temperatures on time at taking into account ionization, charge exchange, ion heating by the electron beam, ion energy exchange and ion escape processes were calculated in [10].
The experimental data of the Kr current at the EBIS Krion-S exit measured over an ion extraction time of 100 μs and the calculated results obtained at $j_e=1.77 \times 10^{21}$ 1/(cm$^2$·s), $U_e=7 \times 10^3$ eV, $N_{Kr}(0)=6 \times 10^9$ cm$^{-3}$, $r_p=0.015$ cm, $B=1.2$ T, by cooling Kr ions with Ne ones.

The next step was to consider ion cooling processes. The method of ion cooling in EBIS was suggested by E.D. Donets and G.D. Shirkov [8]. Equation systems for charge and energy evolution created for Kr and Ne were solved simultaneously. We supposed that the concentration of Ne atoms ($N_0$) in the electron beam is a constant [10].

According to the model, the processes of Pb ionization in EBIS at close to ultimate parameters (the electron beam current is 10 A and the electron energy is 10 keV) were simulated. The electron gun for the source with the
perveance equals to 3 μA/V³/2 at the cathode diameter of 3.4 mm, the cathode emission density of 111 A/cm², the first anode voltage of 22.3 kV and the second anode one of 10 kV can be produced in the firm “ISTOK” (Friasino, Moscow reg., Russia) [11]. After installation of the e-gun in the EBIS, the value of DC current power at the EBIS collector will be equal to 100 kW.

To avoid problems due to collector heating a pulse regime of ionization is suggested. At the pulse duration is about t=0.1 s the collector system can be cooled by water at the rate of flow is about G=3 l/min. We suppose that the process of electron beam formation to reach the current density 200≤j≤500 A/cm² (as it takes place in Krion-S) won’t be a very difficult problem. The time of ion extraction from the trap can be decreased from 100 μs to 10 μs. Therefore we carried out calculations of Pb atom ionization processes during 0.1 s at j≤200 A/cm² and j≥500 A/cm² by cooling the Pb ions with Ne ones and without one.

The workable numerical model of EBIS has been created. The calculated results for Krion_S are close to the experimental ones. The model made more understandable the influence of different processes in the trap on the EBIS output parameters. It allows us to undertake some attempts to predict future results.

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References